
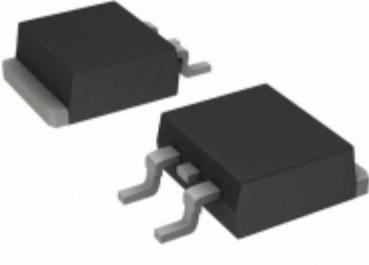
	<h2 style="color: red;">FQB44N10TM</h2> <p><b>Hersteller-Teilenummer:</b> <a href="#">FQB44N10TM</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 100V 43.5A D2PAK</p> <p><b>Datenblätter:</b>  <a href="#">FQB44N10TM.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 34229 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">FQB44N10TM</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	MOSFET N-CH 100V 43.5A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	34229 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 146W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	43.5A (Tc)
Rds On (Max) @ Id, Vgs	39 mOhm @ 21.75A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	62nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1800pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Original-Reel®



















































FQB44N10TM ist neu im Original, Suche FQB44N10TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB44N10TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB44N10TM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQB44N10TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 43.5A D2PAK</p>	 <p><b>FQB45N15V2TM</b> Fairchild/ON Semiconductor MOSFET N-CH 150V 45A D2PAK</p>	 <p><b>FQB3P50TM</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 500V 2.7A D2PAK</p>	 <p><b>FQB3P20TM</b> Fairchild/ON Semiconductor MOSFET P-CH 200V 2.8A D2PAK</p>
 <p><b>FQB45N15V2TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 45A D2PAK</p>	 <p><b>FQB46N15</b> F FQB46N15 F</p>	 <p><b>FQB3P50TM</b> Fairchild/ON Semiconductor MOSFET P-CH 500V 2.7A D2PAK</p>	 <p><b>FQB41N15D</b> FAIRCHILD FAIRCHILD TO-263</p>

### heiße Teile

Mehr

 FQB34N20LTM	 FQB34N20LTM	 FQB34N20TM	 FQB34N20TM_AM002	 FQB34P10
 FQB34P10TM	 FQB34P10TM	 FQB34P10TM_F085	 FQB3N25TM	 FQB3N25TM
 FQB3N30TM	 FQB3N30TM	 FQB3N40TM	 FQB3N40TM	 FQB3N60C
 FQB3N80TM	 FQB3N80TM	 FQB3N90TM	 FQB3N90TM	 FQB3P20TM
 FQB3P20TM	 FQB3P50TM	 FQB3P50TM	 FQB44N10	 FQB44N10TM
 FQB46N15	 FQB46N15TM	 FQB47P06	 FQB47P06TM	 FQB4N20L
 FQB4N20LTM	 FQB4N20LTM	 FQB4N20TM	 FQB4N20TM	 FQB4N25TM
 FQB4N25TM	 FQB4N20TM	 FQB4N50TM	 FQB4N50TM	 FQB4N60C
 FQB4N80TM	 FQB4N80TM	 FQB4N90TM	 FQB4N90TM	 FQB4P25TM
 FQB4P25TM	 FQB50N03	 FQB50N06	 FQB50N06C	 FQB50N06L

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